Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:

Ceramic and metal

Overall Length:

0.292 inches

Mounting Facility Quantity:

1

Mounting Method:

Threaded stud

Thready Qty Per Inch (tpi):

40

Thread Size:

0.112 inches

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

1000.0 reverse voltage, instantaneous

Current Rating Per Characteristic:

10.00 microamperes forward current, average peak

Power Rating Per Characteristic:

18.75 watts any acceptable absolute

Maximum Operating Tempurature Per Measurement Point:

175.0 degrees celsius ambient air

Special Features:

Insluated stud

Thread Series Designator:

Unc

Terminal Type And Quantity:

2 ribbon and 1 threaded stud

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

A110a0